

ON Semiconductor®

# ES1A - ES1D

#### **Features**

- For surface mount applications.
- Glass passivated junction.
- Low profile package.
- · Easy pick and place.
- Built-in strain relief.
- Superfast recovery times for high efficiency.



SMA/DO-214AC COLOR BAND DENOTES CATHODE

### **Fast Rectifiers**

## Absolute Maximum Ratings\* T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value				Units
		1A	1B	1C	1D	Oills
$V_{RRM}$	Maximum Repetitive Reverse Voltage	50	100	150	200	V
I <sub>F(AV)</sub>	Average Rectified Forward Current, @ T <sub>A</sub> =120°C	1.0			А	
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	30			А	
T <sub>stg</sub>	Storage Temperature Range	-50 to +150				°C
T <sub>J</sub>	Operating Junction Temperature	-50 to +150			°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Units		
P <sub>D</sub>	Power Dissipation	1.47	W		
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient*	85	°C/W		
$R_{\theta JL}$	Thermal Resistance, Junction to Lead*	35	°C/W		

<sup>\*</sup>Device mounted on FR-4 PCB 0.013 mm.

# **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter		Device				Units
-			1A	1B	1C	1D	
V <sub>F</sub>	Forward Voltage @ 1.0 A		0.92				V
t <sub>rr</sub>	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{RR} = 0.25 \text{ A}$		15				ns
I <sub>R</sub>	Reverse Current @ rated V <sub>R</sub>	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	5.0 100			μΑ μΑ	
Ст	Total Capacitance V <sub>R</sub> = 4.0 V, f = 1.0 MHz		7.0			pF	

## **Typical Characteristics**

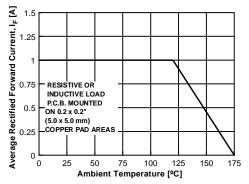


Figure 1. Forward Current Derating Curve

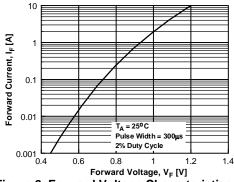


Figure 2. Forward Voltage Characteristics

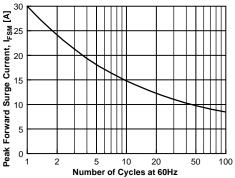


Figure 3. Non-Repetitive Surge Current

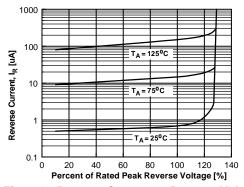
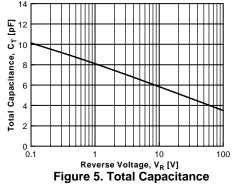
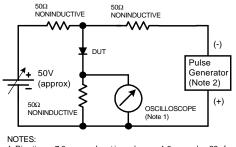
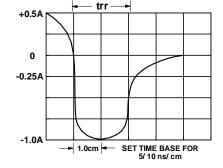


Figure 4. Reverse Current vs Reverse Voltage





1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf. 2. Rise time = 10 ns max; Source impedance = 50 ohms.



Reverse Recovery Time Characterstic and Test Circuit Diagram

ON Semiconductor and III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Semiconductor Components Industries, LLC

www.onsemi.com

# 单击下面可查看定价,库存,交付和生命周期等信息

>>ON Semiconductor(安森美)